# **Question Paper Code: 53B05**

### B.E./B.Tech. DEGREE EXAMINATION, NOV 2018

#### Third Semester

## Biomedical Engineering

#### 15UBM305- SEMICONDUCTOR DEVICES AND CIRCUITS

(Regulation 2015)

Dur	ration: Three hours	num: 100 Marks		
		Answer ALI	Questions	
		PART A - (10 x	1 = 10 Marks)	
1.	Diode is used as			CO1-R
	(a) Current source	(b) Voltage source	(c) Photo diode	(d) Rectifier
2.	If $I_B=1$ mA, $\beta=50$ for	or a transistor, $I_E$ is		CO1-App
	(a) 51 mA	(b) 50 mA	(c) 101 mA	(d) 49 mA
3.	JFET acts as a curren	at source when it is ope	rating	CO2-U
	(a) Along the horizon			
	(c) Along linear part	of drain curve	(d) At $V_{GS} < 0$	
4.	g <sub>m</sub> of MOSFET is co	ontrolled by	_	CO2- R
	(a) Drain-source volt	age (b) Gate-source	voltage (c) Drain curren	nt (d) Gate current
5.	The approximate cur	CO3- R		
	(a) h <sub>ie</sub>	(b) - h <sub>ie</sub>	(c) - h <sub>fe</sub>	(d) $h_{fe}$
6.	Hybrid equivalent c frequencies.	ircuit of a transistor	amplifier is valid at	CO3- U
	(a) Low	(b) High	(c) Very low	(d) Very high
7.	Oscillator is similar t	0		CO4- R
	(a) Rectifier	(b) Amplifier	(c) D.C source	(d) A.C source

8.	The phase shift required by RC phase network in a transistor oscillator is					CO4- R	
	(a) 9	90°	(b) 180°		(c) 360°	(d) 0°	
9.	Bist	able multivibrate	r is	_ in any sta	ate.	C	CO5- R
	(a) S	Stable	(b) Unstab	ole	(c) Saturated	(d) Indepen	dent
10.	Output of an integrator producing waveforms of unequal rise and fall time are called				C	CO5- U	
	(a) Triangular waveform			(b) Sawtooth waveform			
	(c) Pulsating waveform			(d) Spiked waveform			
			PART – B	$(5 \times 3 = 15)$	Marks) (5 Out of 7)		
11.	Define Peak Inverse Voltage of diode.					CO1- R	
12.	BJT as a current controlled device – Justify					CO1- E	
13.	JFET as a Variable Voltage Resistor – Justify					CO2- E	
14.	Compare the operations of Class A and Class B amplifiers.					CO3- Ana	
15.	Point out the advantages of negative feedback.					CO4- Ana	
16.	State and explain Barkhausen criterion for oscillation.					CO4- U	
17.	Differentiate between Astable and Monostable multivibrators.				CO5- Ana		
			PA	RT – C (5	x 15= 75 Marks)		
18.	(a)	(i) Illustrate the	principle of	operation c	of PN junction diode.	CO1- U	(8)
	(ii) Derive an expression for transition and diffusion capacitance of PN junction diode.				CO1- U	(7)	
	(b)	Commore the ex	narotion of w	Or	dar higa airavita, haga higa	CO1 Ano	(15)
	(0)	(b) Compare the operation of voltage divider bias circuits, base bias circuits and Emitter bias circuits.				COI- Ana	(15)
19.	(a)	Summarize the characteristics.	working of J	JFET and c	lraw it's drain and transfer	CO2-U	(15)
				Or			
	(b)	(b) Explain the construction, working of n channel enhancement MOSFET and also draw their characteristics.					(15)

20.	(a)	Determine the h-parameters from transistor characteristics.  Or	CO3- App	(15)
	(b)	Analyze of single stage transistor amplifier using parameters voltage gain, current gain, input impedance and output admittance.	CO3- Ana	(15)
21.	(a)	Interpret the principle of operation and derive the expression for frequency of oscillation for RC phase shift Oscillator.  Or	CO4-U	(15)
	(b)	Draw the circuit of Hartley oscillator and explain its working. Also derive the expressions for frequency of oscillation for starting of oscillation.	CO4-U	(15)
22.	(a)	With neat sketch, explain the operation and characteristics of Astable multivibrator.	CO5-U	(15)
		Or		
	(b)	Illustrate the construction, equivalent circuit and operation of UJT and also explain the characteristics of UJT.	CO5-U	(15)